NSN 5962-01-073-8505

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View Online at https://aerobasegroup.com/nsn/5962-01-073-8505 **Body Length:** Between 1.180 inches and 1.220 inches **Body Width:** Between 0.590 inches and 0.610 inches **Body Height:** Between 0.080 inches and 0.120 inches **Maximum Power Dissipation Rating:** 1000.0 milliwatts **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and programmed and w/enable and w/decoded output and 3-state output and programmable and programmed and w/strobe and expandable and bipolar and schottky and medium speed and w/buffered output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 30331-19-186f29 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life:

Demilitarization: Yes - demil/mli

Unit Of Measure:

N/a

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